



YEA SHIN TECHNOLOGY CO., LTD

MBR2020CT THRU MBR2000CT

20 AMPERE SCHOTTKY BARRIER RECTIFIERS

VOLTAGE - 20 to 200 Volts CURRENT - 20.0 Amperes

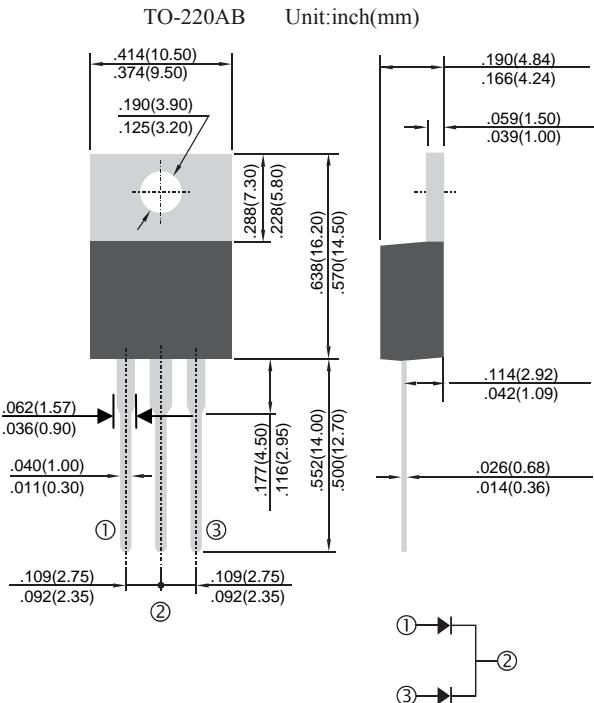


FEATURES

Plastic package has Underwriters Laboratory
 Flammability Classification 94V-0 utilizing
 Flame Retardant Epoxy Molding Compound
 Exceeds environmental standards of MIL-S-19500/228
 Low power loss, high efficiency
 Low forward voltage, high current capability
 High surge capacity
 For use in low voltage, high frequency inverters,
 free wheeling, and polarity protection applications
 High temperature soldering : 260°C / 10 seconds at terminals
 Pb free product available : 99% Sn above meet RoHS
 environment substance directive request

MECHANICAL DATA

Case: TO-220AB molded plastic
 Terminals: Lead, solderable per MIL-STD-202, Method 208
 Polarity: As marked
 Mounting Position: Any



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half wave 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

| SYMBOL | MBR 2020CT | MBR 2030CT | MBR 2040CT | MBR 2045CT | MBR 2050CT | MBR 2060CT | MBR 2080CT | MBR 20100CT | MBR 20150CT | MBR 20200CT | UNIT |
|--|---------------|---------------|---------------|---------------|---------------|---------------|---------------|----------------|----------------|----------------|------|
| Maximum Recurrent Peak Reverse Volt | 20 | 30 | 40 | 45 | 50 | 60 | 80 | 100 | 150 | 200 | V |
| Maximum RMS Volt | 14 | 21 | 28 | 31.5 | 35 | 42 | 56 | 70 | 105 | 140 | V |
| Maximum DC Blocking Volt | 20 | 30 | 40 | 45 | 50 | 60 | 80 | 100 | 150 | 200 | V |
| Maximum Average Forward Rectified Current at TC=90°C | | | | | | | 20.0 | | | | A |
| Peak Forward Surge Current, 8.3ms single half sine wave superimposed on rated load(JEDEC method) | | | | | | | 200 | | 150 | | A |
| Maximum Forward Voltage at 10.0A per element | | | 0.55 | | 0.75 | | 0.85 | | 0.95 | 0.99 | V |
| Maximum DC Reverse Current at Rated TC=25 °C | | | | | 0.1 | | | | 0.025 | | mA |
| DC Blocking Voltage per element TC=100°C | | | | | | 100 | | | 7 | | |
| Typical Thermal Resistance (Note 1) $R_{\theta JA}$ | | | | | 60 | | | | | | °C/W |
| Typical Thermal Resistance (Note 2) $R_{\theta JC}$ | | | | | 5 | | | | | | °C/W |
| Typical Junction Capacitance (Note 3) C_J | | | | | 200 | | | | | | pF |
| Operating and Storage Temperature Range(T_J & T_{stg}) | | | | | | -55 to +150 | | | | | °C |

NOTES:

- 1.Thermal Resistance Junction to Ambient
- 2.Thermal Resistance Junction to Case
- 3.Measured at 1.0MHz and applied reverse voltage of 4.0 volts

DEVICE CHARACTERISTICS

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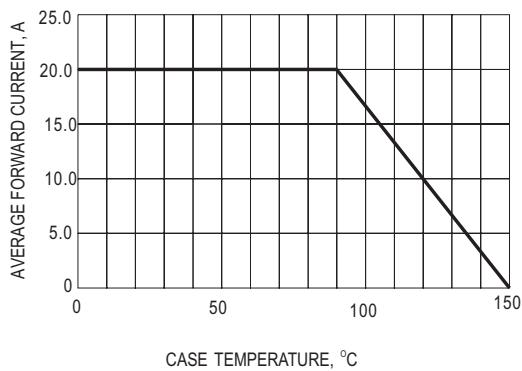


Fig.1- FORWARD CURRENT DERATING CURVE

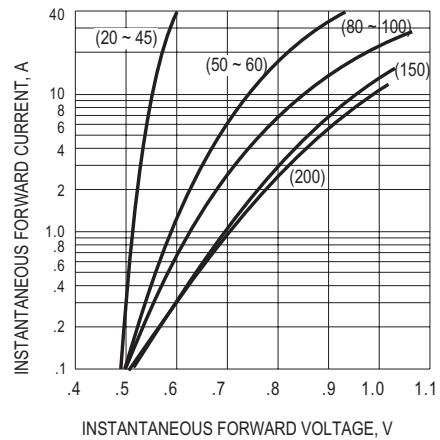


Fig.2- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTIC

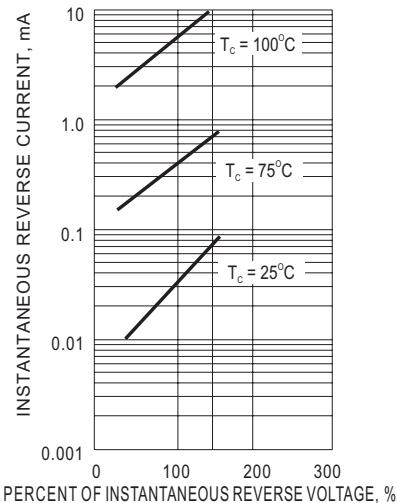


Fig.3- TYPICAL REVERSE CHARACTERISTIC

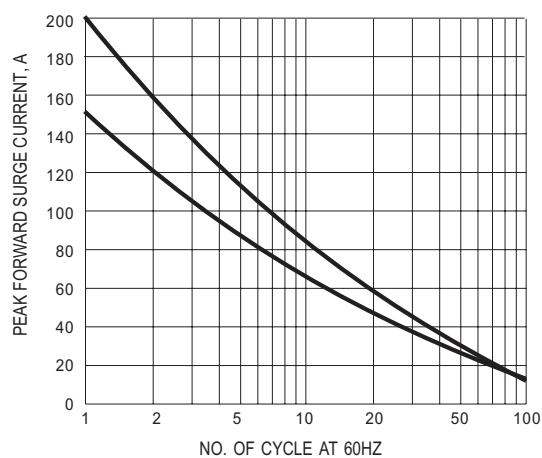


Fig.4- MAXIMUM NON-REPETITIVE SURGE CURRENT

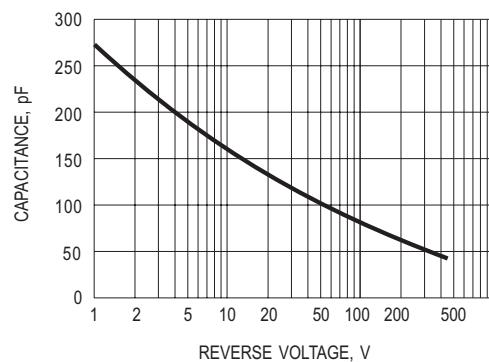


Fig.5- TYPICAL JUNCTION CAPACITANCE